UNISONIC TECHNOLOGIES CO., LTD

MBR1040C

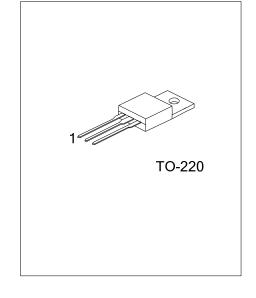
10A SCHOTTKY BARRIER RECTIFIER

DESCRIPTION

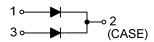
The UTC **MBR1040C** is a Schottky Barrier Rectifier with high efficiency, low power dissipation and high current capacity. It can be applied in high frequency, low voltage inverters, polarity protection and free wheeling applications.

■ FEATURES

- * High surge capability
- * High efficiency, low power dissipation, high current capability, low forward voltage drop
- * Guardring for overvoltage protection



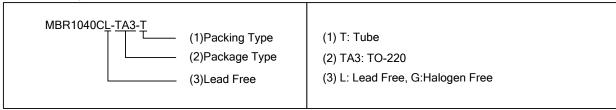
■ SYMBOL



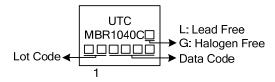
■ ORDERING INFORMATION

Ordering Number		Daalaasa	Pin Assignment			Dooldoo	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MBR1040CL-TA3-T	MBR1040CG-TA3-T	TO-220	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



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MBR1040C

■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _R	40	V
RMS Reverse Voltage		V _{R(RMS)}	28	V
Peak Repetitive Reverse Voltage		V_{RRM}	40	V
Working Peak Reverse Voltage		V_{RWM}	40	V
Average Rectified Output Current (Note 2	ctified Output Current (Note 2) Per Leg		5	
$T_{\rm C} = 105^{\circ}{\rm C}$	Total	l _o	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	125	А
Repetitive Peak Reverse Surge Current	t≤2.0µs	I _{RRM}	1.0	Α
Operating Temperature		TJ	-65 ~ +150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	60	9 0 // //
Junction to Case	θ_{JC}	4.5	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Forward Voltage Drop (Per Leg) (Note 2)	V _{FM}	$I_F=5A, T_C = 25^{\circ}C$			0.60	- V I	
		I _F =5A, T _C = 125°C			0.50		
		I _F =10A, T _C = 25°C			0.80	V	
		I _F =10A, T _C = 125°C			0.75		
Peak Reverse Current at Rated DC		I _F =5A, T _C =25°C			100	μΑ	
Blocking Voltage (Note 2)	I _{RM}	I _F =5A, T _C =125°C			15	mA	
Typical Junction Capacitance (Note)	CJ				150	pF	
Voltage Rate of Change (Rated V _R)	dV/dt				1000	V/µs	

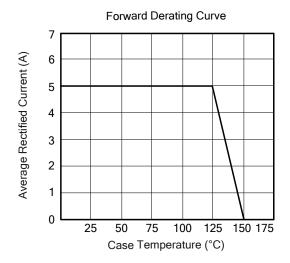
Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC

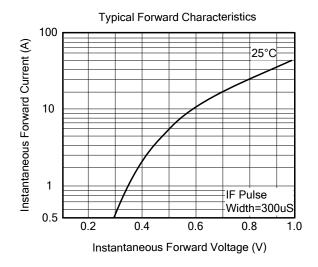
^{2.} Thermal resistance junction to case mounted on heatsink.

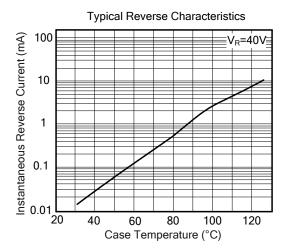
^{2.} Pulse Test: Pulse Width = 300µs, Duty Cycle ≤ 2.0%

MBR1040C DIODE

■ TYPICAL CHARACTERISTICS







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